

Quarterly Reliability Monitoring Results

Quarters: Q1/2022 to Q4/2023

Based on structural similarity

Supplier Nexperia B.V. Name of Laboratory Assembly reliability labs Based on AEC-Q101 Test		User Part Number BCX51-Q Part Description												
									Nexperia DHAM Small Signal Bipolar Transistor					
									SMD package					
		Test Conditions	Duration	# Lots	# Quantity	# Rejects								
			TEST											
			Pre- and Post-Stress											
# E1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below								
		JESD22-A113												
	no.	Bake Tamb = 125 °C	24 hours											
# A 1	PC Preconditioning	Soak Tamb = 85 °C, RH = 85% Reflow soldering	168 hours 3 cycles	1674	70400	0								
# A1	Freconditioning		3 Cycles	1674	70490	0								
	HTRB	MIL-STD-750-1 M1039 Method A												
		Tj = Tjmax, Vr = 100% of max. datasheet												
# B1	Bias	reverse voltage	1000 hours	415	18680	0								
	тс	JESD22-A104												
# A4	Temperature Cycling	-65 °C to Tjmax, not to exceed 150°C	1000 cycles	343	15360	0								
# A3 or	UHAST	JESD22-A118												
# A3 Or	Unbiased HAST	Tamb = 130 °C, RH = 85 %	- 96 hours	362	15920	0								
	46	JESD22-A102												
# A3 alt	AC Autoclave	Tamb = 121 °C, RH = 100 % Pressure = 205 kPa (29.7 psia)												
# A3 all	Autociave	11633die – 203 ki d (23.7 p3id)												
	H3TRB	JESD22-A101												
	High Humidity High	Tamb = 85 °C, RH = 85%, VR = 80 % of												
# A2 alt		rated reverse voltage ^[1]	1000 hours	343	15360	0								
		MIL-STD-750 Method 1037												
	IOL	ton = toff, devices powered to insure ΔTj =												
# A5	Intermittent Operating Life	100 °C for 15000 cycles	1000 hours	343	15360	0								
	RSH	JESD22-A111												
# C8	Resistance to Solder Heat	260 °C ± 5 °C	10 s	283	8490	0								
# C10	SD Solderability	J-STD-002		214	6420	0								
# CIU	Soluciability	J 31D 002		214	6420	0								

^[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

Calculation of FIT and MTTF

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia	Small Signal Bipolar				
DHAM	Transistor	18680	0	0,23	4,40E+09

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